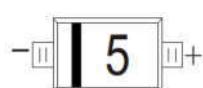
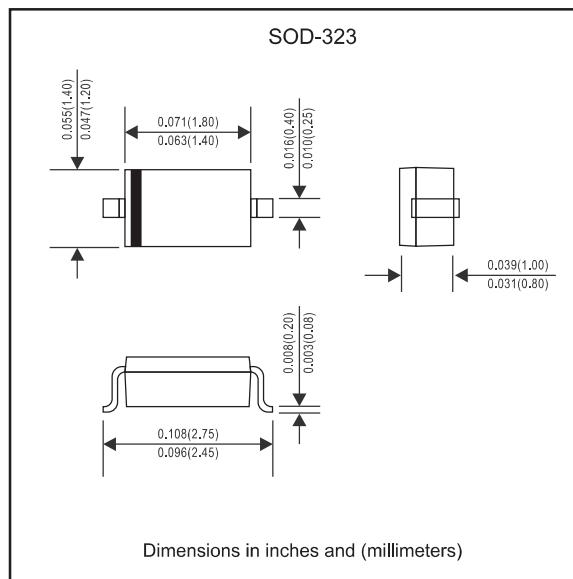


FEATURES

- Low current rectifier schottky diode
- Low voltage, low inductance
- For power supply

MAKING: 5

Package outline

Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

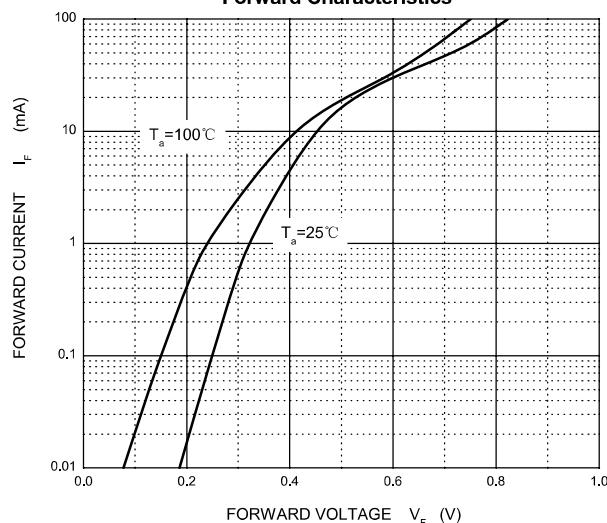
Parameter	Symbol	Limit		Unit
Peak reverse voltage	V _{RM}	40		V
DC reverse voltage	V _R	30		V
Mean rectifying current	I _O	0.03		A
Non-repetitive Peak Forward Surge Current@t=8.3ms	I _{FSM}	0.2		A
Power dissipation	P _D	200		mW
Thermal Resistance Junction to Ambient	R _{θJA}	500		°C/W
Operating Junction Temperature Range	T _j	-40 ~ +125		°C
Storage Temperature Range	T _{stg}	-55 ~ +150		°C

Electrical Ratings @Ta=25°C

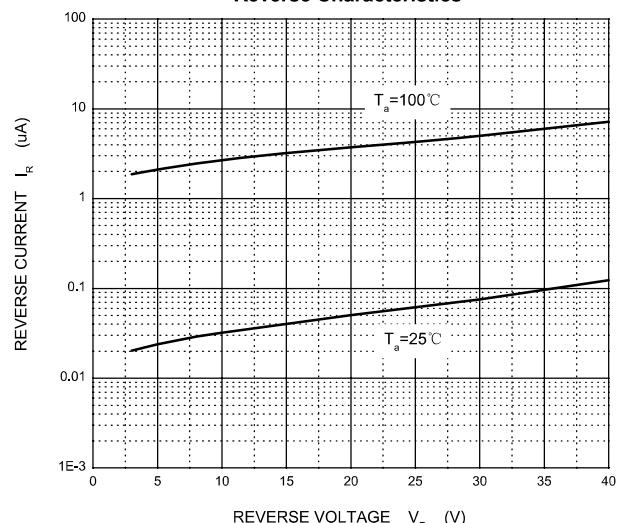
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V _F			0.37	V	I _F =1mA
Reverse current	I _R			0.5	μA	V _R =30V
Capacitance between terminals	C _T		2		pF	V _R =1V, f=1MHZ

Typical Characteristics

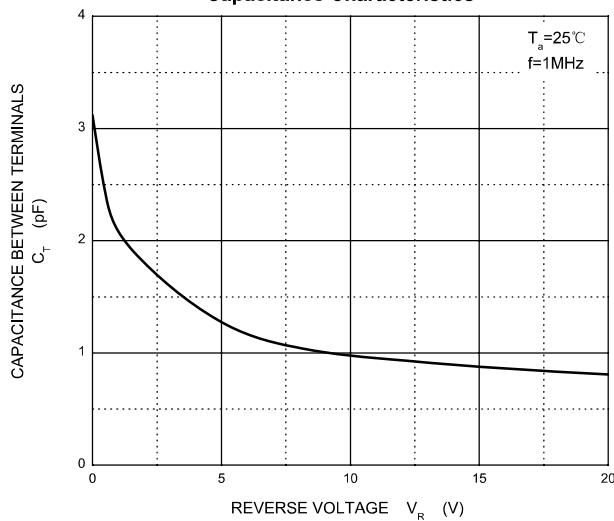
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

